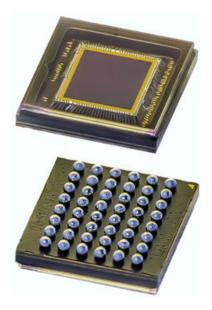


# Compact and high-sensitivity 1.5 megapixel RGB-NIR global shutter image sensors







#### **Features**

- Cutting-edge performance of ST proprietary pixel:
  - BSI structure: Provides superior QE, MTF, and angular response.
  - Full DTI technology: Further increases sensitivity and sharpness.
  - Versatile imaging: Benefits both color and NIR (850 nm, 940 nm) image capture.
  - Reliable supply: Proprietary technology from ST foundry in France, ensures a safe supply.
- Easy integration into your system:
  - Ultracompact die: Centered design to minimize your system size.
  - Small optical format: 4.6 mm (1/4") at full resolution and 3.7 mm (1/5") with 1 MP crop.
  - Low-power consumption: Ideal for battery-powered devices.
  - Robust design: Ensures high image quality at various temperatures.
- A complete toolbox of in-sensor features:
  - Stunning images: Achieved with in-sensor AE and various corrections.
  - Data optimization: Multiple features to optimize data size and frame rates such as crop, and programmable sequences.
  - Enhanced controls: 8 GPIOs enabling extra controls such as trigger or LED synchronization.
- Seamless connection to embedded processing platforms:
  - MIPI CSI-2 interface: 1 or 2 lanes enabling direct connection to entrylevel cost-effective processing platforms.
  - Turnkey solutions: Start your development immediately with our sensor boards, modules, and drivers for the VD16GZ, VB16GZ image sensors.
- The VD16GZ, VB16GZ color and near infrared image sensors are also available in monochrome (VB56G3, VD56G3) and color RGB (VB66GY, VD66GY) versions.

#### **Description**

The VD16GZ, VB16GZ are part of the new generation of image sensors developed by STMicroelectronics for professional and consumer vision applications. Leveraging state-of-the-art technologies developed by ST's own foundry, the sensors provide outstanding performance in color and near infrared. With their RGB-NIR pattern, the VD16GZ, VB16GZ are perfectly suited for multispectral imaging and for the many applications requiring the simultaneous capture of both color and near infrared images.



## **Application**

- Home and service robots
- Smart appliances
- Agriculture
- Drones and UAVs
- Industrial robots and AGVs
- Quality inspection
- 3D stereo imaging
- Security and biometrics

DS14163 - Rev 3 page 2/42



# 1 Acronyms and abbreviations

Table 1. Acronyms and abbreviations

Acronym/abbreviation	Definition		
ADC	analog to digital converter		
AE	autoexposure		
AGV	automated guided vehicle		
AR	augmented reality		
CCI	camera control interface		
СР	charge pump		
CRA	chief ray angle		
CSI	camera serial interface		
DTI	deep trench isolation		
EMC	electromagnetic compatibility		
EMI	electromagnetic interference		
FoV	field of view		
fps frames per second			
GPIO	general-purpose input/output		
I <sup>2</sup> C	inter-integrated circuit (bus)		
ISL	intelligent status line		
ISP	image signal processor		
LDO	low dropout regulator		
LED	light-emitting diode		
MCU	microcontroller unit		
MIPI	mobile industry processor interface		
MTF	modulation transfer function		
NIR	near infrared		
OIF	output interface		
OTP	one-time programmable		
PLL	phase-locked loop		
PWM	pulse-width modulation		
QE	quantum efficiency		
RI	relative illumination		
SW	software		
UAV	unmanned aerial vehicle		
UI user interface for host to sensor communic			
VR virtual reality			

DS14163 - Rev 3 page 3/42



### 2 Product overview

#### 2.1 Functional description summary

The VD16GZ, VB16GZ are designed to be mounted in a system equipped with a dual bandpass filter lens. The organization of the RGB-NIR 4x4 kernel is optimized for the generation of high contrast NIR images and high-quality RGB images. These images are obtained after external host processing applying NIR removal and debayerization.

The The VD16GZ, VB16GZ are 1.5-megapixel global shutter image sensors featuring a matrix of 1124 x 1364 pixels. With their global shutter operation, all pixels are synchronized to capture light at the same time. This removes the motion blur that can affect rolling shutter image sensors, when capturing changing or moving scenes.

Once the exposure is finished, each pixel information is transferred in a storage node, before being read and digitized one pixel row after the other. The image data are digitized using internal 10-bit ADCs. Additional gains can be applied before ADC stage (for example, analog gain) or after ADC stage (for example, digital gain). Following the digital conversion, various image preprocessing and correction algorithms can be applied into the sensors before data output, such as autoexposure or binning.

The image data are output as frames of RAW8 or RAW10 data through a MIPI CSI-2 interface. The sensors can be configured to operate with either 1 or 2 MIPI CSI-2 lanes to best fit with host processing requirements.

The VD16GZ, VB16GZ are synchronized to the rest of the system by means of an external clock, triggers, and general-purpose input/output (GPIO) signals that can be used to enable synchronization of several sensor readouts or to control strobe light sources during exposure time.

The devices are fully configurable through the I<sup>2</sup>C serial interface and provides flexible frame-to-frame parameter configuration changes via the use of programmable contexts. It also embeds a one-time programmable (OTP) nonvolatile memory to be written by 32-bit words.

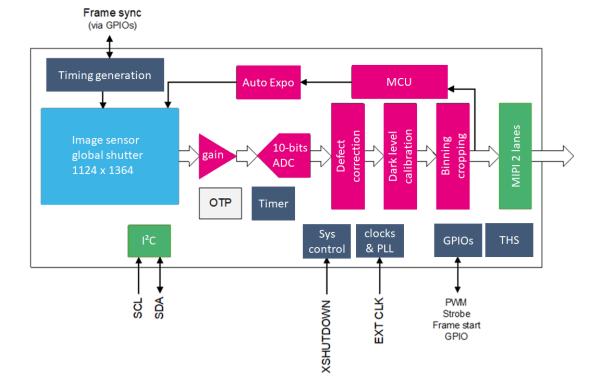


Figure 1. Functional block diagram

DS14163 - Rev 3 page 4/42



# 2.2 Technical specifications summary

Table 2. Technical specifications

Category	Parameter	VD16GZ, VB16GZ specifications
	Resolution	1.53 MP
Resolution	Pixel array [H x V]	1124 x 1364
	Aspect ratio	5:6
	Shutter type	Global shutter
Pixel	Illumination type	Back side illuminated (BSI)
	Pixel size	2.61 μm
Color	Color option	RGB-NIR
	Full resolution	88 fps
Frame rates (maximum)	1 MP resolution	121 fps
	VGA resolution	237 fps
	Pixel array size [H x V]	2.93 mm x 3.56 mm
Optical characteristics	Optical format	1/4" (4.61 mm)
	CRA	30° linear
	Die footprint [H x V]	3.65 mm x 4.34 mm
Mechanical characteristics	Die centering (optical vs. mechanical)	Yes
	Die pinout	115 pins
	Operating temperature range	-30 to +85°C
	Sensor data interface	MIPI CSI-2   1 or 2 lanes
	Sensor control interface	I <sup>2</sup> C, up to 1 Mbits/s
Electronic characteristics	Output format	RAW8, RAW10
Electronic characteristics	Supply voltages	2.8 V – 1.8 V – 1.15 V
	External clock frequency	6 to 27 MHz
	Power consumption	145 mW (typical at 60 fps) / 4 mW (Standby)
	Image quality optimization	<ul><li>Autoexposure</li><li>Automatic dark calibration</li><li>Analog and digital gains</li></ul>
Embedded features	Data and frame rate optimization	<ul><li>Cropping</li><li>Context management with up to 4 contexts</li></ul>
	Others	Mirror/Flip     Test pattern generation     Temperature sensor     8 programmable GPIOs for LED control, PWM control, autonomous or controlled external frame start

DS14163 - Rev 3 page 5/42



## Functional description

#### 3.1 Interfaces

#### 3.1.1 Inter-integrated circuit (I<sup>2</sup>C)

The VD16GZ, VB16GZ are configured and controlled via an I<sup>2</sup>C interface operating in either fast mode (up to 400 kHz) or fast mode plus (up to 1 MHz) at 1.8 V. After the MCU boot sequence, the default I<sup>2</sup>C configuration is fast mode plus with a sink capability set to 20 mA. Drive capability can be decreased to 4 mA (fast mode) by writing a dedicated register once the system has booted. Device addressing uses a CCI protocol with 2 byte subaddresses. The default address of the sensors is 0x20 (including R/W bit), and can be overridden:

- Permanently by storing a non-null value in a dedicated OTP register.
- Dynamically with a firmware command when the MCU state is SW\_STANDBY.

#### 3.1.2 Camera serial interface (CSI)

The sensors are ready to connect via a dual lane mobile industry processor interface (MIPI) CSI-2 serial interface. The dual lane MIPI CSI-2 serial interface supports up to 1.5 Gbps per lane. It is the industry standard for low electromagnetic interference (EMI) and excellent electromagnetic compatibility (EMC) high-speed interfacing. The CSI lane number can be lowered to a single lane. Resolution is scalable between RAW8 and RAW10.

## 3.2 Power supplies

The power supplies required by the sensors are:

- 2.8 V for the analog blocks
- 1.8 V for the digital I/Os
- 1.15 V for the core digital logic and MIPI CSI-2 output drivers

The pixel array requires different positive and negative voltages, all internally generated by charge pumps and regulators. Four voltage references, internally generated, need external decoupling capacitors. The internal MCU handles the entire power management of the sensors to guarantee the lowest power consumption at any given time

#### 3.3 Clock and PLL

An input clock is required from an external digital clock source in the range of 6 to 27 MHz. Firmware is preconfigured for a 12 MHz external source clock. Two built-in PLL (phase-locked loop) blocks generate all necessary internal clocks for the pixel array, processing pipe, and output interface.

DS14163 - Rev 3 page 6/42



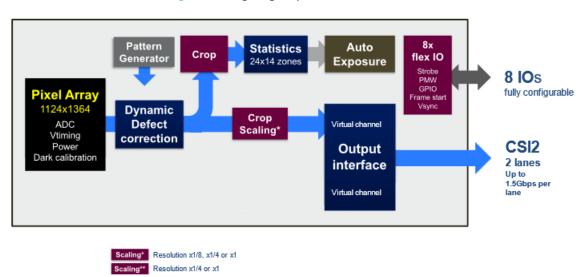
### 3.4 Video pipe

The video pipe performs several features designed to ensure a high quality image. These features include:

- Analog subsampling
- Pattern generation
- Dynamic defective pixel correction
- Dark calibration
- Autoexposure
- Digital binning
- Embedded status lines
- Output interface
- Context management
- Cropping

The diagram below presents the features implementation in the video pipe

Figure 2. Image signal processor schematic



DS14163 - Rev 3 page 7/42

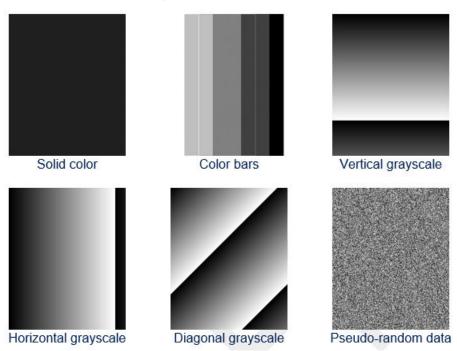


#### 3.4.1 Pattern generation

The pattern generation allows the generation of digital patterns in the output frame for test and debug. It is also possible to insert a cross bar in the image with configurable position, size, and brightness. The available patterns are:

- Solid color
- Color bars
- Vertical gray scale
- Horizontal gray scale
- Diagonal gray scale
- Pseudorandom data

Figure 3. Available patterns



#### 3.4.2 Defective pixel correction

Active pixels are automatically corrected by a dynamic algorithm embedded in the sensor's ISP. This enables defect-free images directly from the sensors without the need for additional algorithm development or processing resources.

The advanced correction algorithm can correct singlet and couplet of defects and take into account local spatial gradients.

The host can program the strength of the correction to find the perfect balance between systematic defect correction and preserving existing textures/patterns in the image. The correction strength evolves automatically with exposure time. This mechanism can be deactivated for debugging purposes and for specific use cases such as structured light.

Because of the specific RGB-NIR 4x4 kernel pattern where blue and red pixel positions toggle along the matrix, defective pixel correction can slightly modify blue and red channel information at transitions. Green and NIR information are not affected.

#### 3.4.3 Dark calibration

Note:

The pixel matrix has dedicated lines with shielded pixels that dynamically retrieve the dark level and subtract it from the active image. Temperature, exposure time, or gain changes are compensated. Temporal smoothing and fractional bit dithering are applied to avoid a sudden one-code step. This block also embeds a programmable digital gain control feature with a granularity of 1/256 followed by a configurable pedestal to offset the dark level along the ISP pipe.

DS14163 - Rev 3 page 8/42



#### 3.4.4 Analog and digital gains

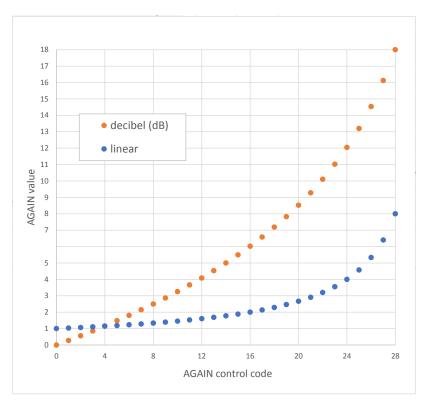
The VD16GZ, VB16GZ enable adjustment of the analog and digital gains on the image to optimize image quality depending on the lighting conditions. Gains are adjusted automatically when autoexposure is enabled, or by manual control when autoexposure is disabled.

Analog gain ranges from x1 (+ 0 dB) up to x8 (+18 dB) with 29 steps following a 1/X behavior enabling to benefit from fine gain granularity at low gain and wider granularity at high gains to better adjust image quality. It follows the following formula:

$$Ana\log gain(x) = \frac{32}{32 - x}$$

Where x is an integer from 0 to 28.





Four digital gains (one per color channel) can be applied, each of them ranging from 1.0 up to 8.0 minus one-step control with a step control of 1/256th so approximately 0.0039.

DS14163 - Rev 3 page 9/42



#### 3.4.5 Autoexposure

The autoexposure (AE) feature computes and automatically applies the ideal exposure time and gain factors to get the optimum average luminance in the image. The autoexposure algorithm is performed directly in the sensors, to benefit from automatic exposure without the need to develop any dedicated algorithm or to allocate processor resources to the computation.

The sensors can also operate in manual mode where exposure parameters are provided by the host.

The host can configure autoexposure module parameters that control brightness target, convergence speed, and stability. The region of interest (ROI) used for autoexposure can be set independently from the image capture region.

A specific antiflickering mode can be selected to mitigate artifacts introduced by ambient light frequency and frame rate differences.

A dedicated I<sup>2</sup>C status register provides the image average brightness information when the sensors are set to autoexposure or manual exposure mode. This information is also available in the status lines (ISL) embedded at the beginning of each frame. Refer to Section 3.4.8: Embedded status lines for ISL description.

#### 3.4.6 Analog subsampling

The devices support x2 and x4 subsampling which reduces overall image size and keeps the same field of view (FoV). Subsampling is applied vertically and horizontally during the ADC readout, where every two or every four pixels are read. When subsampling is used, the frame rate can be increased by decreasing the frame length.

Note: Because of the specific RGB-NIR 4x4 kernel pattern where blue and red pixel positions toggle along the matrix, using analog subsampling (by 2 or by 4) results in a loss of blue or red channel information. Green and NIR information are not affected.

#### 3.4.7 Digital binning

The digital binning process reduces the image resolution by a factor of 2 or 4 in each direction. Central and neighboring pixels are weighted to produce the digital binned image, avoiding special phase shift and artifacts which may occur on the output image. Digital binning and subsampling are mutually exclusive.

Note: Because of the specific RGB-NIR 4x4 kernel pattern where blue and red pixel positions toggle along the matrix, using digital binning (by 2 or by 4) results in a loss of blue or red channel information. Green and NIR information are not affected.

#### 3.4.8 Embedded status lines

The output interface (OIF) embeds the intelligent status line generator, which allows metadata to be sent through the MIPI image data interface. The ISL follows the SMIA CSI-2, simplified, 2-byte, tagged data format for RAW8 data packing. There are two ISL lines transmitted at the beginning of each frame. Each data packet is 256 bytes long. The length of the ISL can be stretched to equal the active line packet size.

The MCU has access to a bank of status registers, refreshed at each frame, and providing detailed information on the current state of the sensors. Most of the content of this bank is also available in ISLs. The ISL contains all information related to the current transmitted frame such as:

- Clock settings
- Cropping and orientation parameters
- Analog and digital gains
- Integration time
- Frame counter index
- Thermal sensor values
- Dark calibration parameters

Transmission of ISL data packets can be disabled by configuring a static register during SW\_STANDBY state before streaming. ISL data packets have their own programmable "data types" and "virtual channels".

DS14163 - Rev 3 page 10/42



#### 3.4.9 Output interface

The output interface (OIF) embeds two data lanes of the MIPI D-PHY interface. It supports up to 1.5 Gbps of data per lane. The OIF outputs active pixel data in RAW10 or RAW8.

The OIF can output a combination of the following:

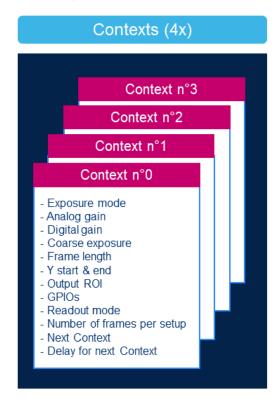
- Intelligent status lines
- Active pixel data

The OIF supports multiple virtual channels and different data types for active pixels and ISL data.

#### 3.4.10 Context management

The sensors allow the configuration of up to four different rolling contexts (or frame setups). Parameters that can be specifically defined in a context are listed in the figure below.

Figure 5. Context parameters

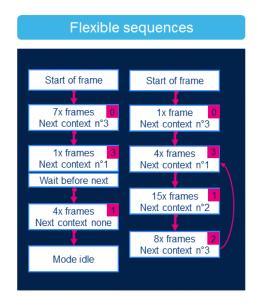


DS14163 - Rev 3 page 11/42



Contexts can be chained one to another in an ending or non-ending sequence.

Figure 6. Example of ending and non-ending multicontext sequence



#### 3.4.11 Cropping

The host can accurately choose which area of the whole pixel array it receives. This reduces traffic on the CSI interface and saves processing time.

#### 3.4.12 Orientation

The sensor's image can be horizontally (mirror) and/or vertically flipped, as illustrated in the following figure.

Figure 7. Image orientation



DS14163 - Rev 3 page 12/42



## 3.5 Synchronization modes

The sensors have multiple synchronization modes:

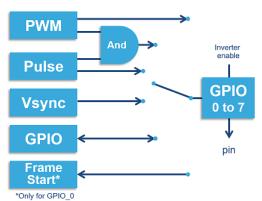
- 1. Leader mode
  - Image streaming starts right after the execution of a streaming initialization command sent over the I<sup>2</sup>C bus
  - After the initialization sequence, wait for a rising edge event on GPIO0 to start streaming images
- 2. Follower mode
  - Using GPIO pulses
  - Using I<sup>2</sup>C triggering commands

### 3.6 General purpose input/outputs (GPIOs)

The sensors provide eight GPIOs:

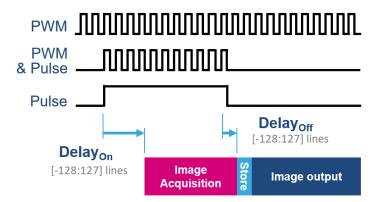
- GPIO0 is used as a frame start synchronization signal or as a generic GPIO if not used for this function
- GPIO[1-7] are used as PWM outputs, pulse (strobe) outputs, VSYNC, or as a generic GPIO, as per the configuration

Figure 8. GPIO modes



All GPIO settings are fully configurable for the four context setups. Each output signal can be mapped to one or several of the GPIOs. All GPIOs have configurable polarity.

Figure 9. PWM and pulse overview



During SW STANDBY state the GPIOs can be controlled as output low/high or input.

DS14163 - Rev 3 page 13/42



## 3.7 Sensor firmware

The sensors present to the host a user interface (bank of registers), accessible via the I<sup>2</sup>C bus.

The host writes high-level parameters in the user interface and an MCU inside the sensors applies the proper sensor configuration based on UI settings provided by the host.

## 3.8 Use case examples

Table 3. Example of functional use cases

Resolution	Maximum fps	Typical data rate
1124 x 1364	88	2 lanes, 800 Mbps per lane
1124 x 1364	88	1 lane, 1500 Mbps
720 x 1280	90	2 lanes, 800 Mbps per lane
640 x 480	210	1 lane at 1500 Mbps
320 x 240	360	1 lane at 1500 Mbps

DS14163 - Rev 3 page 14/42



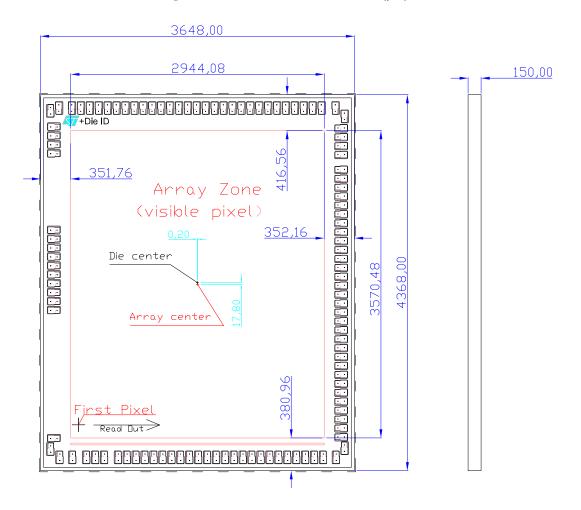
# 4 Die specification

In the table below, the die dimensions are after sawing.

**Table 4. Die dimensions** 

Description	North, (+y) μm	East, (+x) μm	South, (-y) μm	West, (-x) μm
Chip center	0.0	0.0	0.0	0.0
Optical center	_	-0.2	-17.80	_
First active pixel	1767.44	1471.84	-1803.04	-1472.24
First µlens	_	_	_	_
Inner edge of pad	2025.9	1665.9	-2025.9	-1665.9
Center of pad	2065.9	1705.9	-2065.9	-1705.9
Edge of chip	2184 ±10	1824 ±10	-2184 ±10	-1824 ±10
1/2 scribe width	50.0	50.0	50.0	50.0

Figure 10. Die mechanical dimensions (µm)



DS14163 - Rev 3 page 15/42



# 5 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

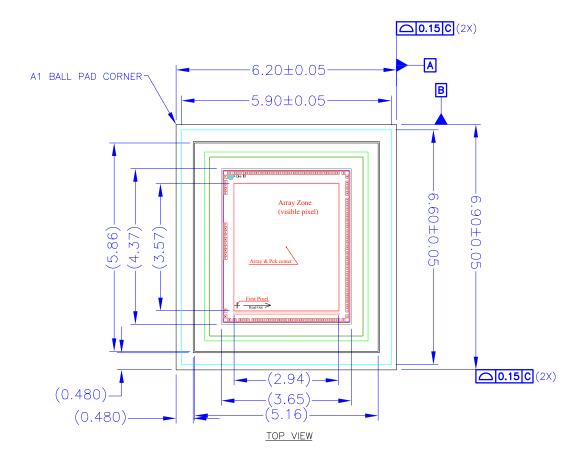
### 5.1 OBGA package information

The bond line thickness (substrate to silicon interface) is 20  $\mu m$ .

The silicon die thickness is 200 µm.

The focusing plan is designed to be on the top surface of the silicon with an height tolerance of  $\pm 30~\mu m$ . Focusing plan tilt is maximum 25  $\mu m$ .

Figure 11. Top view



DS14163 - Rev 3 page 16/42



Figure 12. Side view

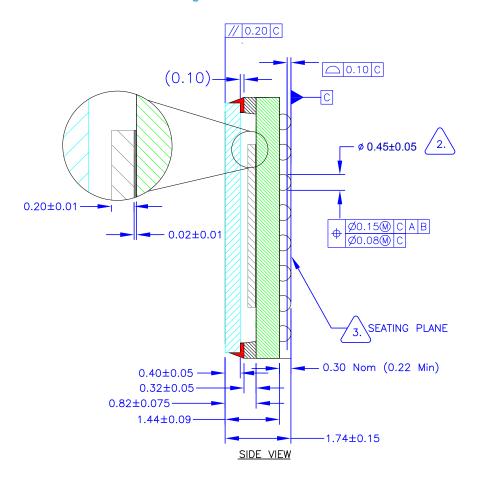
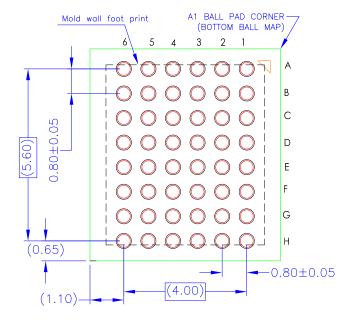


Figure 13. Bottom view



BOTTOM VIEW

DS14163 - Rev 3 page 17/42



## 5.2 Glass reflectance and transmittance

Table 5. Glass reflectance and transmittance

Items		Requirements			
		Band nm	0° (1)	30° <sup>(1)</sup>	5° (1)
Glass optical specification	Transmittance (T)	900-1000	Tminimum > 97.5%	Tminimum > 97%	
Glass optical specification	Reflectivity (R) 900-1	900-1000			Raverage < 1.5%
	Renectivity (R)	900-1000	_		Rmaximum < 2%

<sup>1.</sup> Incidence angle

## 5.3 Soldering information

The OBGA packages are compliant with the RoHS and "green" standards and are qualified for soldering heat resistance according to JEDEC J-STD-020.

237°-245°C 250 1.1-3.0°C/s 1.0°C/s Temp. (0°). **50** ± **10**s to -4°C/s  $0.9 \pm 0.1$ °C/s **T**ime <sub>300</sub> (sec.) 180 210 30 60 120 150 240 270 90

Figure 14. Soldering temperature vs time

Table 6. Soldering details

Profil	Ramp to strike	
Temperature gradient in preheat (T = 70-180°C)	0.9 ± 0.1°C/s	
Temperature gradient (T = 200-225°C)	1.1 - 3.0°C/s	
Peak temperature in reflow	237°C - 245°C	
Time above 220°C	50 ± 10 s	
Temperature gradient in cooling	-1 to -4°C/s (-6°C /s max.)	
Temperature from 50°C to 220°C	160 to 220 s	

DS14163 - Rev 3 page 18/42



# Pin description and assignment

Table 7. Pin description

Pin name	Туре	Description	Reset state	Reference supply
		Power supply		
VCORE		1.15 V power supply for the digital core		1.15 V
VDDIO		1.8 V power supply for I/Os		1.8 V
VANA	PWR	2.8 V analog power supply		2.8 V
DGND		Digital ground		VDDIO
AGND		Analog ground		VANA
		Reference		
LDO2V4		Internal reference (must be connected together)		
VCPNEG_IN		Must be connected to VCPNEG_OUT		
VCPNEG_OUT		Must be connected to VCPNEG_IN		VANA
VCPPOS_IN	REF	Must be connected to VCPPOS_OUT		
VCPPOS_OUT		Must be connected to VCPPOS_IN		
VDDAMP		All VDDAMP (internal reference) must be connected together		VDDIO
		CSI-2 interface		
DATA1P, DATA1N		CSI-2 data lane 1, positive and negative		
DATA2P, DATA2N	MIPI DPHY	CSI-2 data lane 2, positive and negative	Low	VCORE
CLKP, CLKN	KN CSI-2 clock, positive and negative			
		Host interface		
XSHUTDOWN	I	Reset active low		
SDA	I/O	I <sup>2</sup> C data		
SCL	I	I <sup>2</sup> C clock		
GPIO0				
GPIO1				
GPIO2				VDDIO
GPIO3	110	Occasional recognition and attacks likely control	1	VDDIO
GPIO4	I/O	General-purpose I/O and strobe light control	Low	
GPIO5				
GPIO6				
GPI07				
CLKIN	I	Input clock		
		Other pins		
PORTEST	I	Must be connected to digital ground		VDDIO
NC		Not connected		
RCALIB		Not connected		

DS14163 - Rev 3 page 19/42



Table 8. Pin coordinates

The pin coordinates (0, 0) are the die center

Pin number	Bonding point X coordinate	Bonding point Y coordinate	Net name	
1	-1611.62	2065.9	VCPPOS_OUT	
2	-1461.56	2065.9	VANA	
3	-1357.52	2065.9 AG		
4	-1253.97	2065.9	DGND	
5	-1150.42	2065.9	VCORE	
6	-1046.87	2065.9	AGND	
7	-943.32	2065.9	DGND	
8	-839.77	2065.9	VCORE	
9	-736.22	2065.9	VANA	
10	-632.67	2065.9	VANA	
11	-529.12	2065.9	AGND	
12	-425.57	2065.9	VCORE	
13	-322.02	2065.9	NC	
14	-218.47	2065.9	VANA	
15	-114.92	2065.9	NC	
16	-11.37	2065.9	AGND	
17	92.18	2065.9	VANA	
18	195.73	2065.9	DGND	
19	299.28	2065.9	VCORE	
20	402.83	2065.9	DGND	
21	506.38	2065.9	VANA	
22	609.93	2065.9	AGND	
23	713.48	2065.9	VANA	
24	817.03	2065.9	AGND	
25	920.62	2065.9	DGND	
26	1024.17	2065.9	DGND	
27	1127.77	2065.9	SDA	
28	1231.32	2065.9	SCL	
29	1334.87	2065.9	VCORE	
30	1438.42	2065.9	XSHUTDOWN	
31	1600.34	2065.9	VDDIO	
32	1705.9	1969.53	NC	
33	1705.9	1798.29 GPI		
34	1705.9	1694.72 PORTS		
35	1705.9	1591.15 DGND		
36	1705.9	1487.58 GPIO1		
37	1705.9	1316.29 GPIO2		
38	1705.9	1212.71 DGND		
39	1705.9	1109.14 VCORE		
40	1705.9	1005.58	DGND	

DS14163 - Rev 3 page 20/42



Pin number	ber Bonding point X coordinate Bonding point Y coordinate		Net name
41	1705.9	902	VCORE
42	1705.9	798.44	DGND
43	1705.9	694.87	LDO2V4
44	1705.9	591.29	VCORE
45	1705.9	487.73	DGND
46	1705.9	384.16	VDDIO
47	1705.9	280.58	GPIO3
48	1705.9	177.02	VCORE
49	1705.9	73.44	DGND
50	1705.9	-30.13	GPIO4
51	1705.9	-133.69	NC
52	1705.9	-237.26	VCORE
53	1705.9	-340.83	DGND
54	1705.9	-444.41	DGND
55	1705.9	-547.98	DGND
56	1705.9	-651.54	VCORE
57	1705.9	-755.12	AGND
58	1705.9	-858.69	GPIO5
59	1705.9	-962.25	GPIO6
60	1705.9	-1065.83	GPIO7
61	1705.9	-1169.39	VDDIO
62	1705.9	-1272.96	VANA
63	1705.9	-1376.54	LDO2V4
64	1705.9	-1480.11	DGND
65	1705.9	-1583.67	VCORE
66	1705.9	-1687.25	DGND
67	1705.9	-1790.82	CLKIN
68	1705.9	-1959.03	VDDIO
69	1611.63	-2065.9	DGND
70	1461.52	-2065.9	DGND
71	1357.95	-2065.9	VDDAMP
72	1254.38	-2065.9	VCORE
73	1150.81	-2065.9	DGND
74	1047.24	-2065.9	DGND
75	943.67	-2065.9	DATA2N
76	840.1	-2065.9	DATA2P
77	736.53	-2065.9	VDDAMP
78	632.96	-2065.9 CLKN	
79	529.39	-2065.9	DGND
80	425.82	-2065.9	CLKP
81	322.25	-2065.9	VCORE

DS14163 - Rev 3 page 21/42

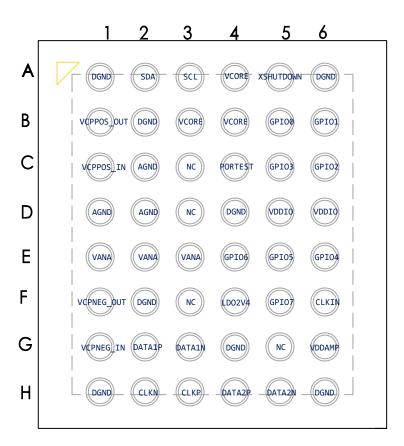


82         218.68         -2065.9         VDDAMP           83         115.11         -2065.9         DATAIN           84         11.54         -2065.9         DATAIP           85         -92.03         -2065.9         DGND           86         -195.6         -2065.9         LDOZV4           87         -299.17         -2065.9         VDDAMP           88         -402.74         -2065.9         DGND           89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2065.9         AGND           92         -817.02         -2065.9         NC           94         -1081.63         -2065.9         NC           94         -1081.63         -2065.9         AGND           95         -1185.2         -2065.9         AGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           99         -1705.9         -1808.5         VCPNEG_IN           100	Pin number	Bonding point X coordinate	Bonding point Y coordinate	Net name
84         11.54         -2065.9         DATA1P           85         -92.03         -2065.9         DGND           86         -195.6         -2065.9         LDO2V4           87         -299.17         -2065.9         VDDAMP           88         -402.74         -2065.9         RCALIB           89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2265.9         AGND           92         -817.02         -2065.9         AGND           93         -920.59         -2065.9         NC           94         -1081.63         -2065.9         NC           95         -1185.2         -2065.9         DGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           98         -1601.12         -2065.9         VANA           99         -1705.9         -1808.5         VCPNEG_IN           100         -1705.9         -321.68         VCPNEG_IN           101         -1705.9         -218.11         AGND           103 <td>82</td> <td>218.68</td> <td>-2065.9</td> <td>VDDAMP</td>	82	218.68	-2065.9	VDDAMP
85         .92.03         .2065.9         DGND           86         .195.6         .2065.9         LDO2V4           87         .299.17         .2065.9         VDDAMP           88         .402.74         .2065.9         RCALIB           89         .506.31         .2065.9         DGND           90         .609.88         .2065.9         VCORE           91         .713.45         .2065.9         AGND           92         .817.02         .2065.9         AGND           93         .920.59         .2065.9         NC           94         .1081.63         .2065.9         NC           95         .1185.2         .2065.9         DGND           96         .1288.77         .2065.9         VCORE           98         .1601.12         .2065.9         VCORE           98         .1601.12         .2065.9         VCNE           98         .1601.12         .2065.9         VCNE           99         .1705.9         .1808.5         VCPNEG_IN           100         .1705.9         .1808.5         VCPNEG_IN           101         .1705.9         .218.11         AGND           103 </td <td>83</td> <td>115.11</td> <td>-2065.9</td> <td>DATA1N</td>	83	115.11	-2065.9	DATA1N
86         -195.6         -2065.9         LDO2V4           87         -299.17         -2065.9         VDDAMP           88         -402.74         -2065.9         RCALIB           89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2065.9         AGND           92         -817.02         -2065.9         AGND           93         -920.59         -2065.9         NC           94         -1081.63         -2065.9         NC           95         -1185.2         -2065.9         DGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           98         -1601.12         -2065.9         VANA           99         -1705.9         -1969.53         AGND           100         -1705.9         -1808.5         VCPNEG_IN           101         -1705.9         -218.11         AGND           102         -1705.9         -141.54         DGND           103         -1705.9         -11.45.4         DGND           104 <td>84</td> <td>11.54</td> <td>-2065.9</td> <td>DATA1P</td>	84	11.54	-2065.9	DATA1P
87         -299.17         -2065.9         VDDAMP           88         -402.74         -2065.9         RCALIB           89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2065.9         AGND           92         -817.02         -2065.9         AGND           93         -920.59         -2065.9         NC           94         -1081.63         -2065.9         NC           95         -1185.2         -2065.9         DGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           98         -1601.12         -2065.9         VANA           99         -1705.9         -1969.63         AGND           100         -1705.9         -1808.5         VCPNEG_IN           101         -1705.9         -321.68         VCPNEG_OUT           102         -1705.9         -218.11         AGND           103         -1705.9         -114.54         DGND           104         -1705.9         -10.97         VANA           10	85	-92.03	-2065.9	DGND
88         -402.74         -2065.9         RCALIB           89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2065.9         AGND           92         -817.02         -2065.9         AGND           93         -920.59         -2065.9         NC           94         -1081.63         -2065.9         NC           95         -1185.2         -2065.9         DGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VANA           99         -1705.9         -1969.53         AGND           100         -1705.9         -1808.5         VCPNEG_IN           101         -1705.9         -218.11         AGND           102         -1705.9         -218.11         AGND           103         -1705.9         -114.54         DGND           104         -1705.9         -10.97         VANA           105         -1705.9         92.6         VANA           106         -1705.9         196.17         NC           107	86	-195.6	-2065.9	LDO2V4
89         -506.31         -2065.9         DGND           90         -609.88         -2065.9         VCORE           91         -713.45         -2065.9         AGND           92         -817.02         -2065.9         AGND           93         -920.59         -2065.9         NC           94         -1081.63         -2065.9         NC           95         -1185.2         -2065.9         DGND           96         -1288.77         -2065.9         VCORE           98         -1601.12         -2065.9         VCORE           98         -1601.12         -2065.9         VANA           99         -1705.9         -1969.53         AGND           100         -1705.9         -1808.5         VCPNEG_IN           101         -1705.9         -321.68         VCPNEG_OUT           102         -1705.9         -218.11         AGND           103         -1705.9         -218.11         AGND           104         -1705.9         -10.97         VANA           105         -1705.9         92.6         VANA           106         -1705.9         196.17         NC           107	87	-299.17	-2065.9	VDDAMP
90	88	-402.74	-2065.9	RCALIB
91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 196.17 NC 109 -1705.9 196.17 NC 100 -1705.9 196.17 NC 101 -1705.9 196.17 NC 102 -1705.9 196.17 NC 103 -1705.9 196.17 NC 104 -1705.9 196.17 NC 105 -1705.9 196.17 NC 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 196.17 NC 109 -1705.9 196.17 NC 110 -1705.9 196.17 NC 110 -1705.9 196.17 NC 111 -1705.9 196.18 VCPPOS_IN 112 -1705.9 1498.25 VCPPOS_IN 113 -1705.9 1498.25 VCPPOS_IN 114 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1705.38 VANA	89	-506.31	-2065.9	DGND
92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 100 -1705.9 -218.11 AGND 103 -1705.9 -218.11 AGND 104 -1705.9 -218.11 AGND 105 -1705.9 -218.11 AGND 106 -1705.9 -218.11 AGND 107 -1705.9 -218.11 AGND 108 -1705.9 -218.11 NC 109 -1705.9 -206.0 VANA 106 -1705.9 -206.0 VANA 107 -1705.9 -206.0 VANA 108 -1705.9 -206.0 VANA 109 -1705.9 -206.0 VANA 100 -1705.9 -206.0 VANA 101 -1705.9 -206.0 VANA 102 -1705.9 -206.0 VANA 103 -1705.9 -206.0 VANA 104 -1705.9 -206.0 VANA 105 -1705.9 -209.74 NC 107 -1705.9 -209.74 NC 108 -1705.9 -209.74 NC 109 -1705.9 -209.74 NC 110 -1705.9 -209.74 NC 111 -1705.9 -209.74 NC 112 -1705.9 -209.74 NC 113 -1705.9 -209.74 NC 114 -1705.9 -209.74 NC 115 -1705.9 -209.74 NC 116 -1705.9 -209.74 NC 117 -1705.9 -209.74 NC 118 -1705.9 -209.74 NC 119 -1705.9 -209.74 NC 110 -1705.9 -209.74 NC 111 -1705.9 -209.74 NC 112 -1705.9 -209.74 NC 113 -1705.9 -209.74 NC 114 -1705.9 -209.74 NC 115 -2065.9 NC 116 -2065.9 NC 116 -2065.9 NC 117 NC 117 NC 118 NC 119 NC 110 NC 1	90	-609.88	-2065.9	VCORE
93	91	-713.45	-2065.9	AGND
94 -1081.63 -2065.9 NC  95 -1185.2 -2065.9 DGND  96 -1288.77 -2065.9 AGND  97 -1451.06 -2065.9 VCORE  98 -1601.12 -2065.9 VANA  99 -1705.9 -1808.5 VCPNEG_IN  101 -1705.9 -218.11 AGND  102 -1705.9 -218.11 AGND  103 -1705.9 -114.54 DGND  104 -1705.9 -10.97 VANA  105 -1705.9 92.6 VANA  106 -1705.9 196.17 NC  107 -1705.9 196.17 NC  108 -1705.9 196.17 NC  109 -1705.9 196.17 NC  109 -1705.9 196.17 NC  110 -1705.9 196.17 NC  110 -1705.9 196.17 NC  110 -1705.9 196.17 NC  111 -1705.9 A03.31 NC  112 -1705.9 1498.25 VCPPOS_IN  112 -1705.9 1601.82 VCORE  113 -1705.9 1705.38 VANA	92	-817.02	-2065.9	AGND
95	93	-920.59	-2065.9	NC
96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -114.54 DGND 105 -1705.9 9-10.97 VANA 106 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 506.88 VCORE 110 -1705.9 1498.25 VCPPOS_IN 111 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	94	-1081.63	-2065.9	NC
97 -1451.06 -2065.9 VCORE  98 -1601.12 -2065.9 VANA  99 -1705.9 -1969.53 AGND  100 -1705.9 -1808.5 VCPNEG_IN  101 -1705.9 -321.68 VCPNEG_OUT  102 -1705.9 -218.11 AGND  103 -1705.9 -114.54 DGND  104 -1705.9 -114.54 DGND  105 -1705.9 92.6 VANA  106 -1705.9 92.6 VANA  107 -1705.9 196.17 NC  107 -1705.9 196.17 NC  108 -1705.9 403.31 NC  109 -1705.9 506.88 VCORE  110 -1705.9 506.88 VCORE  111 -1705.9 1498.25 VCPPOS_IN  112 -1705.9 1601.82 VCORE  113 -1705.9 1705.38 VANA	95	-1185.2	-2065.9	DGND
98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	96	-1288.77	-2065.9	AGND
99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 506.88 VCORE 110 -1705.9 1498.25 VCPPOS_IN 111 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	97	-1451.06	-2065.9	VCORE
100         -1705.9         -1808.5         VCPNEG_IN           101         -1705.9         -321.68         VCPNEG_OUT           102         -1705.9         -218.11         AGND           103         -1705.9         -114.54         DGND           104         -1705.9         -10.97         VANA           105         -1705.9         92.6         VANA           106         -1705.9         196.17         NC           107         -1705.9         299.74         NC           108         -1705.9         403.31         NC           109         -1705.9         506.88         VCORE           110         -1705.9         610.45         AGND           111         -1705.9         1498.25         VCPPOS_IN           112         -1705.9         1601.82         VCORE           113         -1705.9         1705.38         VANA           114         -1705.9         1808.95         AGND	98	-1601.12	-2065.9	VANA
101       -1705.9       -321.68       VCPNEG_OUT         102       -1705.9       -218.11       AGND         103       -1705.9       -114.54       DGND         104       -1705.9       -10.97       VANA         105       -1705.9       92.6       VANA         106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1601.82       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	99	-1705.9	-1969.53	AGND
102       -1705.9       -218.11       AGND         103       -1705.9       -114.54       DGND         104       -1705.9       -10.97       VANA         105       -1705.9       92.6       VANA         106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1601.82       VCPPOS_IN         112       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	100	-1705.9	-1808.5	VCPNEG_IN
103       -1705.9       -114.54       DGND         104       -1705.9       -10.97       VANA         105       -1705.9       92.6       VANA         106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	101	-1705.9	-321.68	VCPNEG_OUT
104       -1705.9       -10.97       VANA         105       -1705.9       92.6       VANA         106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	102	-1705.9	-218.11	AGND
105       -1705.9       92.6       VANA         106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	103	-1705.9	-114.54	DGND
106       -1705.9       196.17       NC         107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	104	-1705.9	-10.97	VANA
107       -1705.9       299.74       NC         108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	105	-1705.9	92.6	VANA
108       -1705.9       403.31       NC         109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	106	-1705.9	196.17	NC
109       -1705.9       506.88       VCORE         110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	107	-1705.9	299.74	NC
110       -1705.9       610.45       AGND         111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	108	-1705.9	403.31	NC
111       -1705.9       1498.25       VCPPOS_IN         112       -1705.9       1601.82       VCORE         113       -1705.9       1705.38       VANA         114       -1705.9       1808.95       AGND	109	-1705.9	506.88	VCORE
112     -1705.9     1601.82     VCORE       113     -1705.9     1705.38     VANA       114     -1705.9     1808.95     AGND	110	-1705.9	610.45	AGND
113     -1705.9     1705.38     VANA       114     -1705.9     1808.95     AGND	111	-1705.9	1498.25	VCPPOS_IN
114 -1705.9 1808.95 AGND	112	-1705.9	1601.82	VCORE
	113	-1705.9	1705.38	VANA
115 -1705.9 1959.04 VANA	114	-1705.9	1808.95	AGND
	115	-1705.9	1959.04	VANA

DS14163 - Rev 3 page 22/42



Figure 15. Ball positions (see-through view)



DS14163 - Rev 3 page 23/42



# 7 Application schematic

## 7.1 Additional components

Dedicated additional capacitors are required to complete the circuit. These are listed in Table 9. Capacitor needs below. The capacitors should be selected to maintain their capacitance value within the indicated tolerance over the full range of maximum voltages, operating temperatures, and aging.

Capacitor values are based on capacitor positions (embedded in the camera module or external to the camera module).

External capacitors are required to properly filter out supply noise. Optimal reference in terms of value and size is subject to application board architecture and topology. The external capacitor values provided in the table below may be increased to compensate real supply noise.

Table 9. Capacitor needs

Associated pin name	Capacitor position	Typical voltage	Minimum capacitance	Typical capacitance	Maximum capacitance	Operating frequencies	Capacitor ground	Purpose
CPPOS_IN, CPPOS_OUT	Embedded	3.55 V	330 nF	470 nF	560 nF	160 MHz	AGND	CP tank capacitor
CPNEG_IN, CPNEG_OUT	Embedded	-2.0 V	650 nF	0.88 μF	1.04 µF	160 MHz	AGND	CP tank capacitor
VDDIO	Embedded	1.8 V				1 MHz	DGND	Supply
VDDIO	External	1.0 V	1 μF			INITZ	DGND	decoupling
	Embedded		470 nF			800 MHz 1 GHz -	DGND	Supply decoupling
VCORE		1.15 V				1.5 GHz		Supply
	External		10 μF			160 MHz - 200 MHz	DGND	decoupling
VANA	Embedded	2.0.1/	100 nF			160 MHz	AGND	Supply
VAINA	External	2.8 V	10 µF	160 IVIHZ	AGND	decoupling		
LDO2V4	Embedded	2.4 V	100 nF		1 μF	DC	AGND	LDO capacitor
VDDAMP	Embedded	1.15 V	100 nF		1 μF	1.5 GHz	DGND	Supply decoupling

DS14163 - Rev 3 page 24/42

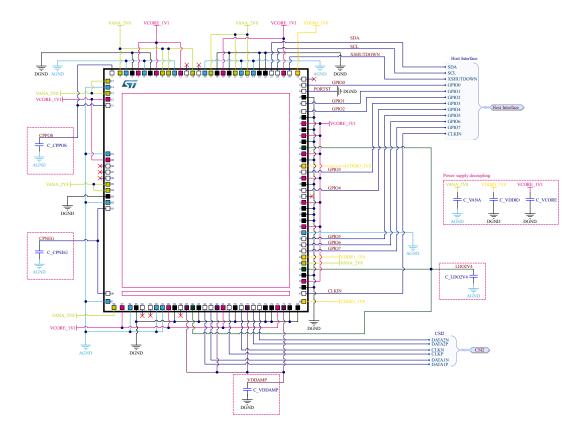
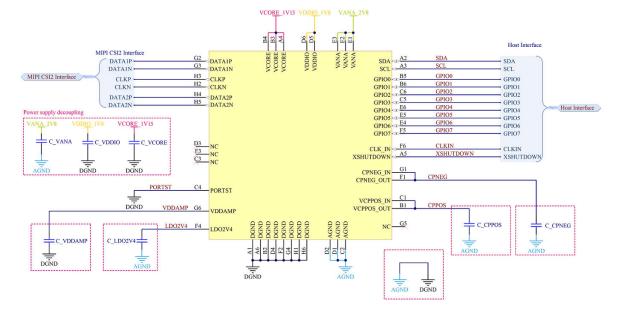


Figure 16. Application schematic for bare die

Figure 17. Application schematic for OBGA



DS14163 - Rev 3 page 25/42



#### 7.2 Layout guidelines

For good PCB design practice, observe the following image sensor layout:

- Use power and ground planes to supply power to the sensors.
- Join grounds i.e. join AGND and DGND into one single, solid GND plane underneath the sensors.
- Connect this GND plane to the sensor's pins with one via per GND pin.
- To minimize risk of emissions, shield all vias and tracks attached to supplies by their respective GND nets.
- Maximize copper fill on the power planes near the sensors and use vias to improve heat transfer from the sensors. Consider including additional heatsinks close to the sensors if they are to be used at high temperatures.
- Route the high-speed signal pairs of the MIPI CSI-2 interface with balanced and controlled impedance differential traces (50 Ω single-ended impedance, 100 Ω differential impedance). This is a requirement for high-speed signaling. Route each pair together and match them in length to target a maximum 10 ps skew.

VCPNEG\_IN and VCPNEG\_OUT must be connected together with a short track. The required decoupling capacitor shall be placed on this path and not on an isolated track.

VCPPOS\_IN and VCPPOS\_OUT must be connected together with a short track. The required decoupling capacitor shall be placed on this path and not on an isolated track.

## 7.3 Device power up sequence

To power on the devices:

- Provide all the external supplies (VCORE, VDDIO, VANA) according to the device characteristics described in Section 9: Electrical characteristics. As long as XSHUTDOWN is low, the devices are in HW\_STANDBY state.
- You can switch on the external supplies and CLKIN in any order.
- Set XSHUTDOWN to high.

Figure 18. Power up sequence



The devices have power-on-reset (POR) detection cells with hysteresis on VCORE and VDDIO power supplies. POR is released after a typical delay of 20 µs on the rising edge.

Bursts with a duration of less than 2 µs (typical) are ignored.

Table 10. POR typical threshold

Supply	POR typical threshold rising edge (V)	POR typical threshold falling edge (V)
VCORE	0.65	0.55
VDDIO	1.1	0.95

DS14163 - Rev 3 page 26/42



# 7.4 Device power down sequence

The power down sequence must be done as follows:

- 1. If the sensors are in STREAMING state, then set them to SW\_STANDBY state and wait for the command to complete.
- 2. Set XSHUTDOWN to low.
- 3. External supplies can be switched off in any order, as well as CLKIN.

DS14163 - Rev 3 page 27/42



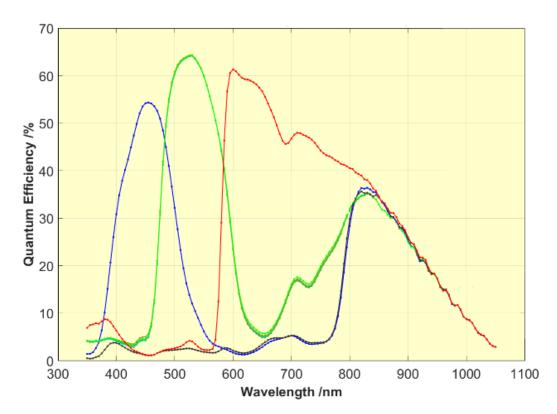
# 8 Pixel performance

The information listed in this section is for typical parts at ambient temperature (Tj = 40°C).

## 8.1 Quantum efficiency

Quantum efficiency (QE) is the percentage of incident photons converted into electrons.





DS14163 - Rev 3 page 28/42



#### 8.2 MTF

The modulation transfer function (MTF) measures the ability of the devices to differentiate spatial frequencies. The MTF value represents the contrast restitution for the corresponding spatial frequency. In other words, it describes the contrast attenuation. It is a sharpness indicator that quantifies the extent to which image sensors can capture and discriminate fine detailed contrast of objects within the field of view.

The figure below presents the on-axis MTF, measured in a 100x100 pixel ROI using the slanted-edge method, following ISO12233 sfrmat5. Note that in the following figure, Ny is the spatial Nyquist frequency.

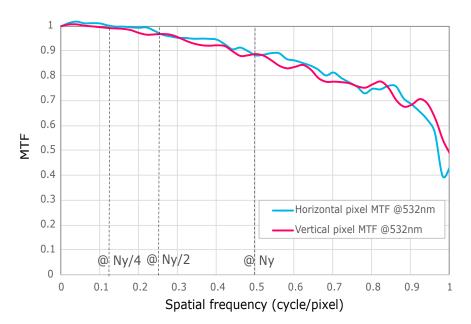
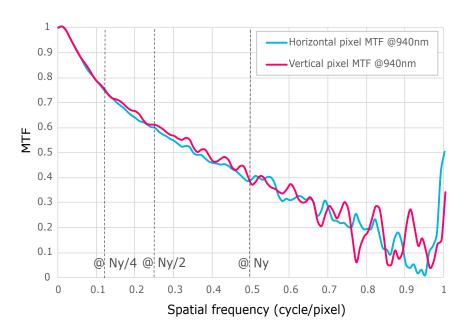


Figure 20. On-axis vertical and horizontal pixel MTF @ 532 nm





DS14163 - Rev 3 page 29/42



### 8.3 Color pattern

The VD16GZ, VB16GZ are color and NIR image sensors featuring a 4x4 pattern that is sensitive to red, green, blue and NIR (see figure below).

(0,0)**IR IR** GG GG GG **RR** GG BB GG IR GG IR **RR** GG BB GG

Figure 22. VD16GZ, VB16GZ 4x4 pattern

## 8.4 Microlenses and CRA matching

Each pixel of the matrix has its own microlens covering it.

The purpose of the microlens is to concentrate and optimize photon capture by passing through the module lens down to the photo diode to increase sensor light sensitivity and to maximize the amount of light received by each pixel.

The light beam has an incidence angle change when passing through the module lens, increasing from center to periphery. This is the chief ray angle (CRA).

To compensate for the change of CRA over the matrix, the microlens position over the pixels progressively shifts from matrix center to matrix borders.

The design of the sensor's microlens shift is optimized for matching a lens with CRA of 30° at corners and follows a linear shift shape.

It is recommended to match the CRA of the lens with the CRA of the image sensors to maximize image quality. Featuring advanced BSI pixel technology, the VD16GZ, VB16GZ provide high relative illumination (RI) uniformity up to the image corners, which enables users to select lenses with different CRA with limited impact.

The following figure presents the CRA tolerance range in lens selection for maintaining a RI uniformity over 90% across the image.

DS14163 - Rev 3 page 30/42



Figure 23. Guideline for lens CRA matching

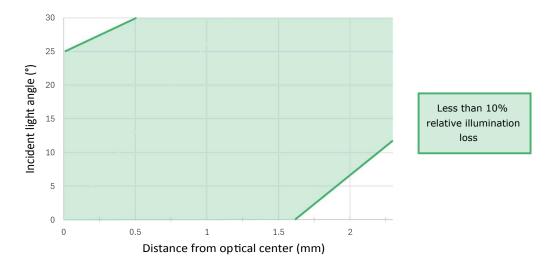
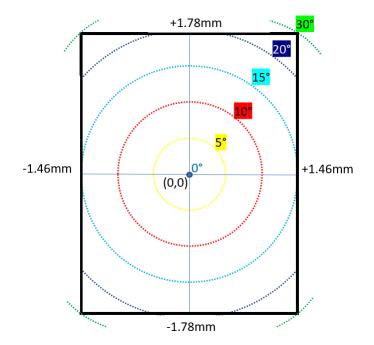


Figure 24. Co-centric pixel microlens CRA shift



DS14163 - Rev 3 page 31/42



## 9 Electrical characteristics

The electrical characteristics have been measured under the following typical conditions:

- Full resolution (1124 x 1364)
- 60 fps
- Nominal power supply levels
- External clock at 12 MHz
- Junction temperature at 60°C
- Nominal voltage

## 9.1 Absolute maximum ratings

Caution:

Stresses above those listed under "Absolute maximum ratings" may cause permanent damage to the devices. This is a stress rating only and functional operation of the devices at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 11. Absolute maximum ratings

Symbol	Parameter	Max	Unit
VDDIO	Digital I/O power supply	2.5	V
VANA	Analog power supply	3.5	V
VCORE	Digital core power supply	1.4	V
VESD, electrostatic discharge	Human body model (HBM)	±2	kV
model	Charge device model (CDM)	±500	V

## 9.2 Operating conditions

Table 12. Operating conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
VDDIO	Digital IO power supply	1.7	1.8	1.9	
VANA	Analog power supply	2.65	2.8	2.95	V
VCORE	Digital core power supply	1.08	1.15	1.26	
		Tempe	erature		
T JF	Junction temperature (functional operation)	-30	_	85	°C

DS14163 - Rev 3 page 32/42



### 9.3 Power consumption

Table 13. Typical power consumption

Values below are measured for the conditions listed in Section 9: Electrical characteristics, but they also include process variability.

State	VDDIO (nominal)		VCORE (nominal)		VANA (nominal)		Unit	Total power					
State	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	Тур.	Max.	Unit
Reset	0.0075	0.013	0.017	0.2	2.1	6.5	0.028	0.038	0.05		2.5	_	
SW_STANDBY	0.0075	0.013	0.017	1	3.3	7.5	0.028	0.043	0.05		4	_	
Streaming image 60 fps	7.5	8.5	11.0	50	57	65	18	22.8	25	mA	145	_	mW
Leader mode 30 fps	_	6.8	_	_	49.5	_	_	17.4	_		120	_	
Follower mode 0 fps	_	5.5	_	_	43	_	_	13.5	_		97	_	

Table 14. Maximum supply consumption

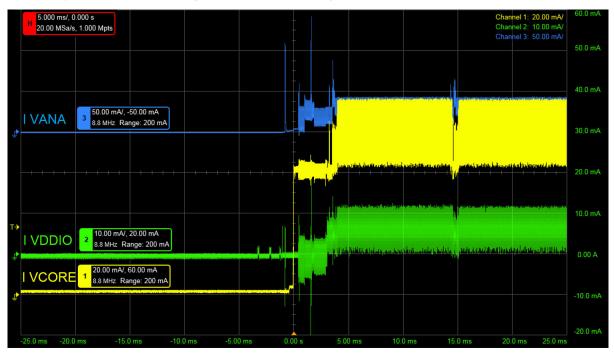
Values below are measured for the worst conditions of process, voltage, and temperature.

State	VDDIO (mA)	VCORE (mA)	VANA (mA)
SW_STANDBY	0.02	23	0.1
Streaming image 60 fps	11	86	25

#### 9.3.1 Current profile

Figure 25 and Figure 26 are evaluated on one device.

Figure 25. Start streaming and the first frame of typical current profile (mA) over time (ms)



Note: Figure 25. Start streaming and the first frame of typical current profile (mA) over time (ms) is captured at maximum temperature and voltage.

DS14163 - Rev 3 page 33/42

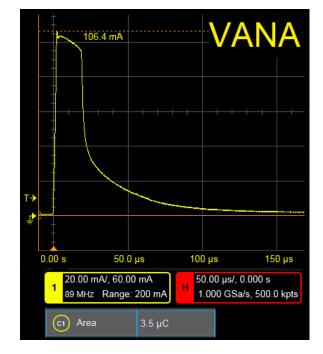


Figure 26. Detail of VANA first transient pulse energy

## 9.4 CLKIN input

 $V_{\text{CLKINL}},\,V_{\text{CLKINH}},\,f_{\text{CLKIN}},\,\text{CtoCjitter, and Duty cycle are evaluated on a limited number of devices}.$ 

**Table 15. Typical CLKIN input** 

The CLKIN input is for all voltage and temperature conditions.

Symbol	Parameter	Min.	Max.	Unit
V <sub>CLKINL</sub>	DC-coupled square wave low-level input	-0.3	0.3 x VDDIO	V
V <sub>CLKINH</sub>	DC-coupled square wave high-level input	0.7 x VDDIO	VDDIO + 0.3	V
f <sub>CLKIN</sub>	Clock input frequency	6	27	MHz
CtoCjitter	Clock maximum cycle-to-cycle jitter	_	200	ps
Duty cycle	Clock duty cycle	40	60	%
I <sub>CLKIN</sub>	Input leakage current	_	10	μA

### 9.5 Digital inputs

Table 16. Digital inputs over process variations at 60°C

Symbol	Parameter	Min.	Max.	Unit
V <sub>IL</sub>	Low-level input voltage	-0.3	0.3 x VDDIO	V
V <sub>IH</sub>	High-level input voltage	0.7 x VDDIO	VDDIO + 0.3	V
I <sub>Leak</sub>	Input leakage current (1)	_	10	μΑ

1. For  $0 \le VI \le VDDIO$ 

DS14163 - Rev 3 page 34/42



## 9.6 Digital outputs

#### **Table 17. Digital outputs**

The digital outputs are over process variations at 60°C.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V <sub>OL</sub>	Low-level output voltage	IOL = -4 mA	_	0.4	V
V <sub>OH</sub>	High-level output voltage	IOH = 4 mA	VDDIO - 0.4V	_	V
I <sub>max</sub>	Maximum current	_	_	4	mA

## 9.7 I<sup>2</sup>C interface - SDA, SCL

The  $I^2C$  timing and voltage conform with the norm: UM10204-I2C-bus specification and user manual, Rev. 6, 4 April 2014.

## 9.8 CSI-2 interface

The CSI-2 interface conforms with the MIPI DPHY specification v1.1.

DS14163 - Rev 3 page 35/42



## 10 Packing information

## 10.1 Package delivery mode

Tested dice are delivered as sawn dice which are reconstructed into a wafer format on UV-tape, and delivered on a metallic ring (see figure below). The frames are packed in plastic containers, each including a maximum of 13 double-spaced reconstructed wafer rings. A mapping information file is also provided for localizing dice that may have been damaged during wafer reconstruction on sticking foil.

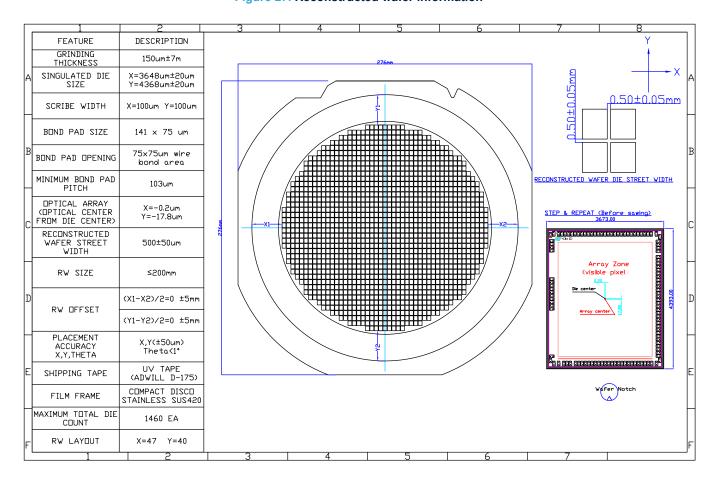


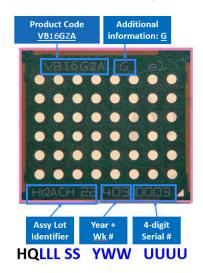
Figure 27. Reconstructed wafer information

DS14163 - Rev 3 page 36/42



## 10.2 Product marking

Figure 28. Product marking example



Product code: VB16GZ Additional information: G Other marking information:

- HQ: Assembly plant code
- LLL: Assembly lot
- SS: Split characters
- Y: Assembly year (last digit of current year)
- WW: Assembly week (2 digits week number of this build)
- UUUU: Serial number (4 digit serial number of units in this build)

DS14163 - Rev 3 page 37/42



#### 10.3 Tape and reel information

 $0.30\pm0.05$ 

R 0.20 MAX

10.8

SECTION B-B

2.00±0.10 4.00 A
A
A
B
O
DETAIL D
SCALE 4: 1

DIM ±
Ao 6.75 0.10

7.45 0.10

2 35 0 10

Figure 29. Reel description



Store all packing material in an appropriate indoor area. This is to prevent any dust and/or damage from the sun, external light, and physical shocks.

Keep the temperature between 15°C and 35°C.

Keep the relative humidity range between 10% and 70% maximum.

Store the reconstructed wafers under vacuum, in their original supplied sealed packing until they are used.

After the packing seal is broken, store the reconstructed wafers under nitrogen (N2) within dedicated closed shelves until they are processed.

Use the trace code to count the storage time. It is written on the package label.

The maximum storage time of the reconstructed wafer is:

- Six months from the trace code date. This is when the wafer is kept in the original sealed packing.
- One week from the trace code date. This is when the original packing seal is open.

SECTION A-A

The maximum storage time defines the maximum time that can be waited for reconstructed wafer processing. Processing may be for picking and placing, and module integration. If the maximum storage time is not respected, safe processing is not guaranteed.

Note: For further information on reconstructed wafer specifications for visual inspection and packing, refer to the technical note TN1497.

DS14163 - Rev 3 page 38/42



# **Revision history**

Table 18. Document revision history

Date	Version	Changes
08-Dec-2022	1	Initial release
07-Oct-2024	2	First public release
		Added the VB16GZ product.
		Updated the document title.
		Updated cover image.
		Updated the Device summary table.
		Updated the Features.
28-Oct-2025	3	Added Section 5.1: OBGA package information, Section 5.2: Glass reflectance and transmittance, and Section 5.3: Soldering information.
		Added Figure 15. Ball positions (see-through view).
		Updated Figure 16. Application schematic for bare die.
		Added Figure 17. Application schematic for OBGA.
		Updated layout of Section 10: Packing information and added Section 10.2: Product marking and Section 10.3: Tape and reel information.

DS14163 - Rev 3 page 39/42



# **Contents**

1	Acro	onyms a	and abbreviations	3					
2	Prod	duct ove	erview	4					
	2.1	Functio	onal description summary	4					
	2.2	Technic	cal specifications summary	5					
3	Fun	ctional c	description	6					
	3.1		ces						
		3.1.1	Inter-integrated circuit (I <sup>2</sup> C)	6					
		3.1.2	Camera serial interface (CSI)	6					
	3.2	Power	supplies	6					
	3.3	Clock a	and PLL	6					
	3.4 Video pipe								
		3.4.1	Pattern generation	8					
		3.4.2	Defective pixel correction	8					
		3.4.3	Dark calibration	8					
		3.4.4	Analog and digital gains	9					
		3.4.5	Autoexposure	10					
		3.4.6	Analog subsampling	10					
		3.4.7	Digital binning	10					
		3.4.8	Embedded status lines	10					
		3.4.9	Output interface						
		3.4.10	Context management						
		3.4.11	Cropping						
		3.4.12	Orientation						
	3.5	•	ronization modes						
	3.6		al purpose input/outputs (GPIOs)						
	3.7	Sensor	r firmware	14					
	3.8		ase examples						
4	Die	specific	ation	15					
5	Pac	kage inf	ormation	16					
	5.1	OBGA	package information	16					
	5.2	Glass r	reflectance and transmittance	18					
	5.3	Solderi	ing information	18					
6	Pin	descript	tion and assignment	19					
7			schematic						
	7.1		onal components						
		_	•						



	7.2	Layout guidelines
	7.3	Device power up sequence
	7.4	Device power down sequence
8	Pixel	performance
	8.1	Quantum efficiency
	8.2	MTF
	8.3	Color pattern
	8.4	Microlenses and CRA matching
9	Elect	rical characteristics3
	9.1	Absolute maximum ratings
	9.2	Operating conditions
	9.3	Power consumption
		<b>9.3.1</b> Current profile
	9.4	CLKIN input
	9.5	Digital inputs
	9.6	Digital outputs
	9.7	I <sup>2</sup> C interface - SDA, SCL
	9.8	CSI-2 interface
10	Pack	ing information
	10.1	Package delivery mode
	10.2	Product marking
	10.3	Tape and reel information
	10.4	Storage information
Rev	ision l	history3



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DS14163 - Rev 3 page 42/42